

ALPHANUMERIC INDEX — CROSS-REFERENCE (Continued)

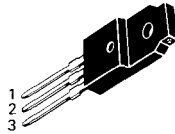
Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number	Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number
MJF127	MJF127		3-1016	MPS-U60	MPS-U60		3-1066
MJF15030	MJF15030		3-1026	MPS-U95	MPS-U95		3-1068
MJF15031	MJF15031		3-1026	MPSU01	MPS-U01		3-1040
MJF2955	MJF2955		—	MPSU01A	MPS-U01A		3-1040
MJF3055	MJF3055		—	MPSU02	MPS-U02		3-1042
MJF47	MJF47		3-1007	MPSU03	MPS-U03		3-1044
MJF6107	MJF6107		3-1022	MPSU04	MPS-U04		3-1044
MJH10012	MJH10012		3-596	MPSU05	MPS-U05		3-1048
MJH11017	MJH11017		3-1034	MPSU06	MPS-U06		3-1048
MJH11018	MJH11018		3-1034	MPSU07	MPS-U07		3-1050
MJH11019	MJH11019		3-1034	MPSU10	MPS-U10		3-1052
MJH11020	MJH11020		3-1034	MPSU11		MPS-U10	3-1052
MJH11021	MJH11021		3-1034	MPSU12		MPS-U45	3-1055
MJH11022	MJH11022		3-1034	MPSU45	MPS-U45		3-1055
MJH12004	MJH12004		3-644	MPSU51	MPS-U51		3-1058
MJH12005	MJH12005		—	MPSU51A	MPS-U51A		3-1058
MJH13090	MJH13090		3-688	MPSU52	MPS-U52		3-1060
MJH13091	MJH13091		3-758	MPSU55	MPS-U55		3-1062
MJH16002	MJH16002		3-976	MPSU56	MPS-U56		3-1062
MJH16002A	MJH16002A		3-734	MPSU57	MPS-U57		3-1064
MJH16004	MJH16004		3-976	MPSU60	MPS-U60		3-1066
MJH16006	MJH16006		3-742	MPSU95	MPS-U95		3-1068
MJH16006A	MJH16006A		3-750	NSD102		2N4923	3-79
MJH16008	MJH16008		3-742	NSD103		2N4923	3-79
MJH16010	MJH16010		3-758	NSD104		2N4923	3-79
MJH16010A	MJH16010A		3-766	NSD105		2N4923	3-79
MJH16012	MJH16012		3-758	NSD106		2N4923	3-79
MJH16018	MJH16018		3-782	NSD131		MJE340	3-876
MJH16032	MJH16032		3-984	NSD132		MJE340	3-876
MJH16034	MJH16034		3-984	NSD133		MJE340	3-876
MJH6282	MJH6282		3-1030	NSD134		MJE340	3-876
MJH6283	MJH6283		3-1030	NSD135		MJE340	3-876
MJH6284	MJH6284		3-1030	NSD151		MJE800	3-888
MJH6285	MJH6285		3-1030	NSD152		MJE800	3-888
MJH6286	MJH6286		3-1030	NSD202		2N4919	3-75
MJH6287	MJH6287		3-1030	NSD203		2N4919	3-75
MJH6676	MJH6676		3-758	NSD204		2N4919	3-75
MJH6677	MJH6677		3-758	NSD205		2N4919	3-75
MJH6678	MJH6678		3-758	NSD206		2N4919	3-75
MPC900			3-143	NSD3439		MJE3439	3-908
MPS-U01	MPS-U01		3-1040	NSD3440		MJE3440	3-908
MPS-U01A	MPS-U01A		3-1040	NSDU01		MPS-UC1	3-1040
MPS-U02	MPS-U02		3-1042	NSDU01A		MPS-UC1A	3-1040
MPS-U03	MPS-U03		3-1044	NSDU05		MPS-U05	3-1048
MPS-U04	MPS-U04		3-1044	NSDU06		MPS-U06	3-1048
MPS-U05	MPS-U05		3-1048	NSDU07		MPS-U07	3-1050
MPS-U06	MPS-U06		3-1048	NSDU45		MPS-U45	3-1055
MPS-U07	MPS-U07		3-1050	NSDU51		MPS-U51	3-1058
MPS-U10	MPS-U10		3-1052	NSDU51A		MPS-U51A	3-1058
MPS-U11			3-1052	NSDU55		MPS-U55	3-1062
MPS-U12			3-1055	NSDU56		MPS-U56	3-1062
MPS-U31			3-1048	NSDU57		MPS-U57	3-1064
MPS-U45	MPS-U45		3-1055	NSE170		MJE170	3-862
MPS-U47			3-1048	NSE171		MJE171	3-862
MPS-U51	MPS-U51		3-1058	NSE180		MJE180	3-862
MPS-U51A	MPS-U51A		3-1058	NSE181		MJE181	3-862
MPS-U52	MPS-U52		3-1060	NSP105		TIP42A	3-1083
MPS-U55	MPS-U55		3-1062	NSP2010		TIP42	3-1083
MPS-U56	MPS-U56		3-1062	NSP2011		TIP42A	3-1083
MPS-U57	MPS-U57		3-1064	NSP2021		TIP41A	3-1083

*Consult Motorola if a direct replacement is necessary.

TABLE 5 — PLASTIC TO-220 (continued)

I _C Cont Amps Max	V _{CEO} (sus) Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			f _T MHz Min	P _D (Case) Watts @ 25°C
		NPN	PNP			t _s μs Max	t _f μs Max	@ I _C Amp		
10	60	D44H7	D45H7	20 min	4					50
		D44H8	D45H8	40 min	4					50
			D45H9	40 min	4					50
		MJE2801T		25/100	3					75
		MJE3055T	MJE2955T	20/70	4					75
		2N6387##	2N6667##	1k/20k	5				20#	65
		SE9300##	SE9400##	1k min	4				1#	70
	80	BDX33B##	BDX34B##	750 min	3				3	70
		BD809	BD810	15 min	4				1.5	90
		D44E3##		1000 min	5	2 typ	0.5 typ	10		50
			D45H12	40 min	4					50
		2N6388##	2N6668##	1k/20k	5				20#	65
		D44H10	D45H10	20 min	4	0.5 typ	0.14 typ	5	50 typ	50
12	100	D44H11	D45H11	40 min	4	0.5 typ	0.14 typ	5	50 typ	50
		SE9301##	SE9401##	1k min	4				1#	70
		BDX33C##	BDX34C##	750 min	3				3	70
		SE9302##	SE9402##	1k min	4				1#	70
		MJE13008		6/30	8	3	0.7	8	4	100
		MJE13009		6/30	8	3	0.7	8	4	100
	30	D44VH1	D45VH1	20 min	4	0.7	0.09	8	50 typ	83
		40	2N6486	2N6489	20/150	5	0.6 typ	0.3 typ	5	5
		45	BDW39	BDW44	1 k min	5	1 typ	1.5 typ	5	4
			D44VH4	D45VH4	20 min	4	0.5	0.09	8	50 typ
		60	2N6487	2N6490	20/150	5	0.6 typ	0.3 typ	5	5
			BDW40	BDW45	1 k min	5	1 typ	1.5 typ	5	4
15	80	D44VH7		20 min	4	0.5	0.09	8	50 typ	85
		2N6488	2N6491	20/150	5	0.6 typ	0.3 typ	5	5	75
		BDW41	BDW46	1 k min	5	1 typ	1.5 typ	5	4	85
		D44VH10	D45VH10	20 min	4	0.5	0.09	8	50 typ	83
		100	BDW42	BDW47	1 k min	5	1 typ	1.5 typ	5	4
		120	BDW43	BDW48	1 k min	5	1 typ	1.5 typ	5	4

|h_{FE}| @ 1 MHz, ## Darlington

TABLE 6 — PLASTIC Full Pak (TO-220 Type)

CASE 221C-02

I _C Cont Amps Max	V _{CEO} (sus) Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			f _T MHz Min	P _D (Case) Watts @ 25°C
		NPN	PNP			t _s μs Max	t _f μs Max	@ I _C Amp		
1	250	MJF47		30/150	0.3	2 typ	0.17 typ	0.3	10	28
5	100	MJF122##	MJF127##	2000 min	3	1.5 typ	1.5 typ	3	4#	28
8	80		MJF6107	30/90	2	0.5 typ	0.13 typ	2	4	35
	100	MJF102##	MJF107##	3000 min	3	1.5 typ	1.5 typ	3	4#	35
	150	MJF15030	MJF15031	40 min	3	1 typ	0.15 typ	3	30	35
10	60	MJF3055	MJF2955	20/100	4				2	40

|h_{FE}| @ 1 MHz, ## Darlington

Full Pak

Power Transistor

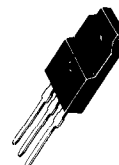
For Isolated Package Applications

Designed for general-purpose amplifier and switching applications, where the mounting surface of the device is required to be electrically isolated from the heatsink or chassis.

- Isolated Overmold Package (1500 Volts RMS Min.)
- Electrically Similar to the Popular 2N6107
- 70 $V_{CEO(sus)}$
- 7 A Rated Collector Current
- No Isolating Washers Required
- Reduced System Cost
- High Current Gain-Bandwidth Product
 $f_T = 4 \text{ MHz (Min) } @ I_C = 500 \text{ mAdc}$

MJF6107

**PNP SILICON
POWER TRANSISTOR
7 AMPERES
70 VOLTS
34 WATTS**



**CASE 221C-02
TO-220 TYPE**

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	70	Vdc
Collector-Base Voltage	V_{CB}	80	Vdc
Emitter-Base Voltage	V_{EB}	5	Vdc
Isolation Voltage (RMS for 1 Min)	V_{ISOL}	1500	Vrms
Collector Current — Continuous — Peak	I_C	7 10	Adc
Base Current	I_B	3	Adc
Total Power Dissipation* @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	34 0.27	Watts W/ $^\circ\text{C}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	2 0.016	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case*	$R_{\theta JC}$	3.7	$^\circ\text{C/W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$
Lead Temperature for Soldering Purpose	T_L	260	$^\circ\text{C}$

*Measurement made with thermocouple contacting the bottom insulated mounting surface (in a location beneath the die), the device mounted on a heatsink with thermal grease and a mounting torque of $\geq 6 \text{ in. lbs.}$

Full Pak is a trademark of Motorola Inc.

MJF6107

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage (1) (I _C = 100 mAdc, I _B = 0)	V _{CEO(sus)}	70	—	Vdc
Collector Cutoff Current (V _{CE} = 80 Vdc, I _B = 0)	I _{CES}	—	1	μAdc
Collector Cutoff Current (V _{CE} = 80 Vdc, V _{EB(off)} = 1.5 Vdc)	I _{CEx}	—	1	μAdc
Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0)	I _{EBO}	—	1	μAdc

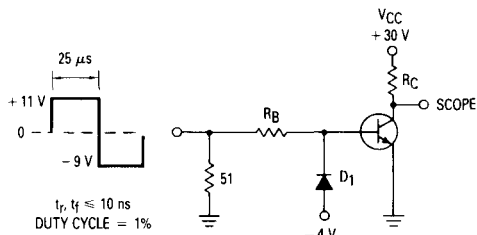
ON CHARACTERISTICS (1)

DC Current Gain (I _C = 2 Adc, V _{CE} = 4 Vdc) (I _C = 7 Adc, V _{CE} = 4 Vdc)	h _{FE}	30 5	90 —	—
Collector-Emitter Saturation Voltage (I _C = 7 Adc, I _B = 3 Adc)	V _{CE(sat)}	—	2	Vdc
Base-Emitter On Voltage (I _C = 7 Adc, V _{CE} = 4 Vdc)	V _{BE(on)}	—	2	Vdc

DYNAMIC CHARACTERISTICS

Current Gain-Bandwidth Product (2) (I _C = 500 mAdc, V _{CE} = 4 Vdc, f _{test} = 1 MHz)	f _T	4	—	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1 MHz)	C _{ob}	—	250	pF
Small-Signal Current Gain (I _C = 0.5 Adc, V _{CE} = 4 Vdc, f = 50 kHz)	h _{fe}	20	—	—

Notes: 1. Pulse Test: Pulse Width ≈ 300 μs, Duty Cycle ≈ 2%.
2. f_T = |h_{fe}| • f_{test}



R_B and R_C VARIED TO OBTAIN DESIRED CURRENT LEVELS

D1 MUST BE FAST RECOVERY TYPE, eg:

MBD5300 USED ABOVE I_B ≈ 100 mA

MSD6100 USED BELOW I_B ≈ 100 mA

Figure 1. Switching Time Test Circuit

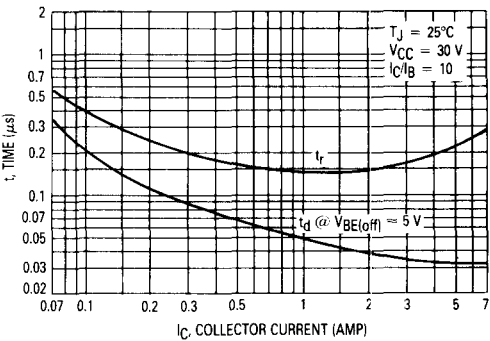


Figure 2. Turn-On Time

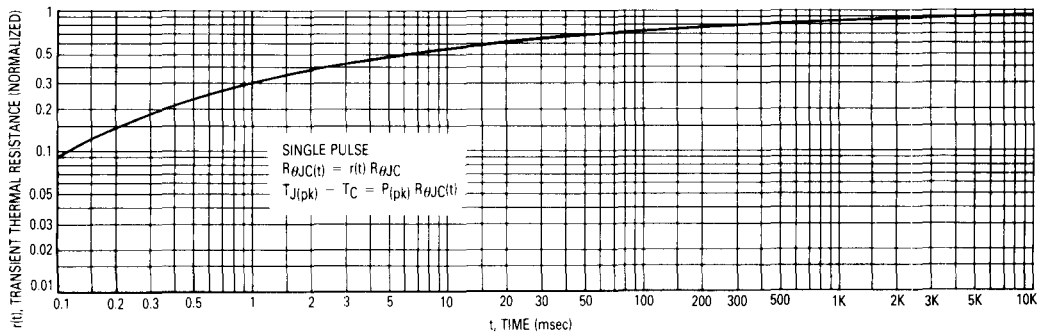


Figure 3. Thermal Response

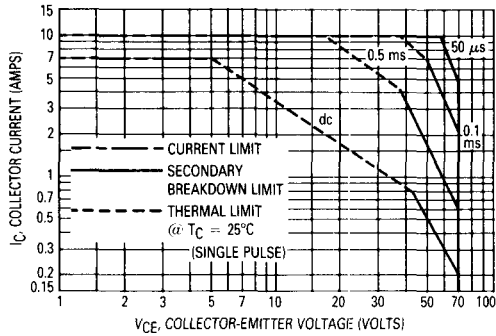


Figure 4. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

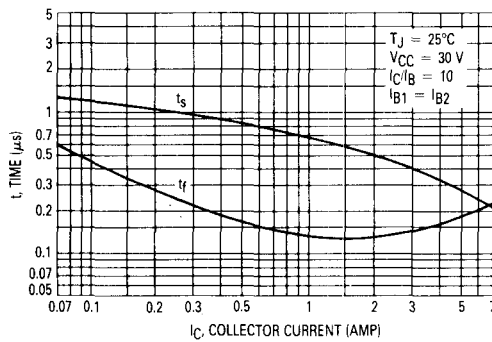


Figure 5. Turn-Off Time

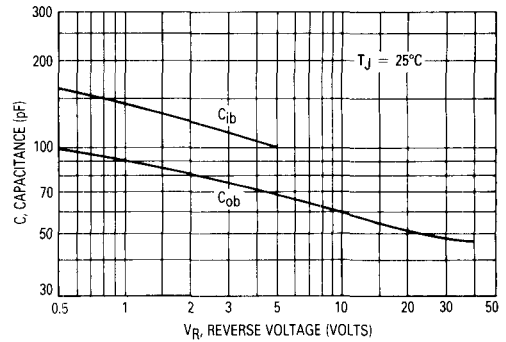


Figure 6. Capacitance

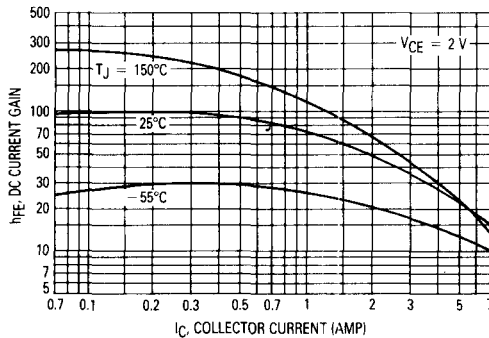


Figure 7. DC Current Gain

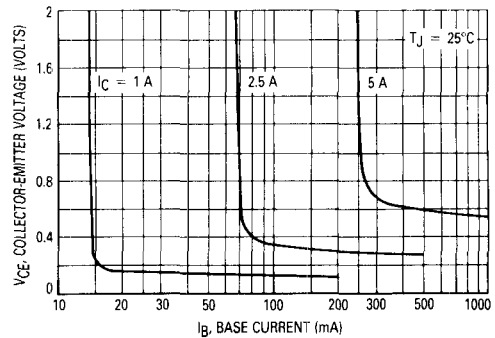


Figure 8. Collector Saturation Region

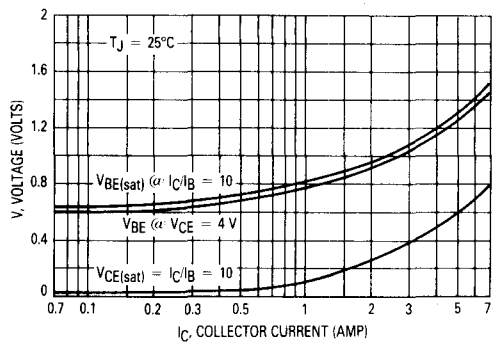


Figure 9. "On" Voltages

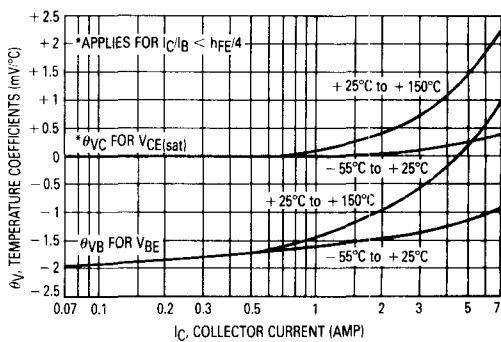


Figure 10. Temperature Coefficients

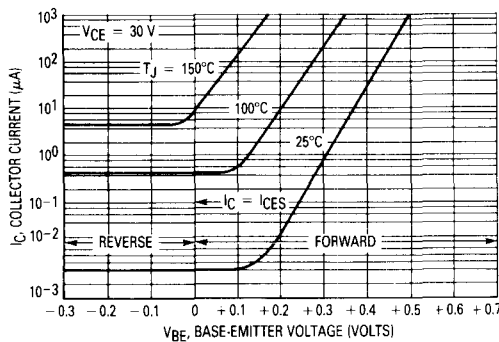


Figure 11. Collector Cut-Off Region

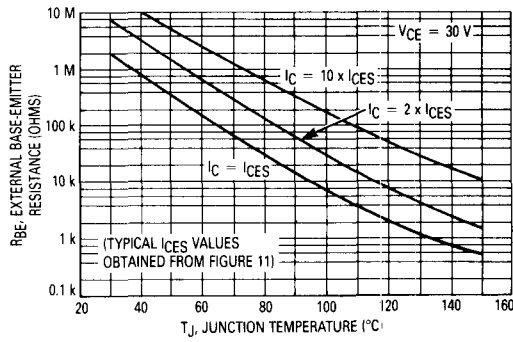


Figure 12. Effects of Base-Emitter Resistance

OUTLINE DIMENSIONS

